

## KSD1589

### **Low Frequency Power Amplifier**

- Low Speed Switching Industrial Use
- Complement to KSB1098



## **NPN Silicon Darlington Transistor**

### Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	150	V
V <sub>CEO</sub>	Collector-Emitter Voltage	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current (DC)	5	А
I <sub>CP</sub>	*Collector Current (Pulse)	8	А
I <sub>B</sub>	Base Current	0.5	А
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1.5	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 100 V, I_{E} = 0$			1	μΑ
h <sub>FE1</sub>	*DC Current Gain	$V_{CE} = 2V, I_{C} = 3A$	2K	6K	15K	
h <sub>FE2</sub>		$V_{CE} = 2V, I_{C} = 5A$	500			
V <sub>CE</sub> (sat)	*Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 3mA$		0.9	1.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 3A, I_B = 3mA$		1.6	2	V
t <sub>ON</sub>	Turn ON Time	$V_{CC} = 50V, I_{C} = 3A$		1		μs
t <sub>stg</sub>	Storage Time	$I_{B1} = -I_{B2} = 3mA$		3.5		μs
t <sub>f</sub>	Fall Time	$R_L = 16.7\Omega$		1.2		μs

<sup>\*</sup> Pulse Test: PW≤350µs, Duty Cycle≤2% Pulsed

## $h_{\mbox{\scriptsize FE}} \mbox{ Classification}$

Classification	R	0	Y	
h <sub>FE1</sub>	2000 ~ 5000	3000 ~ 7000	5000 ~ 15000	

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# **Typical Characteristics**

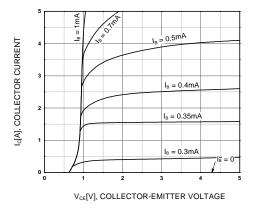


Figure 1. Static Characteristic

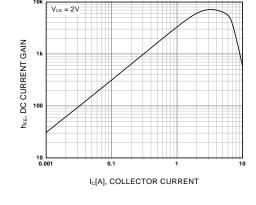


Figure 2. DC current Gain

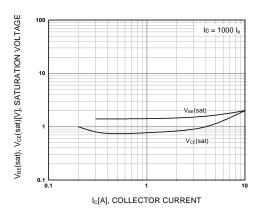


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

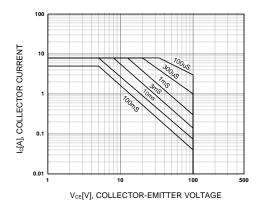


Figure 4. Safe Operating Area

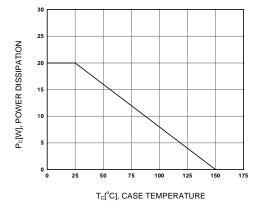
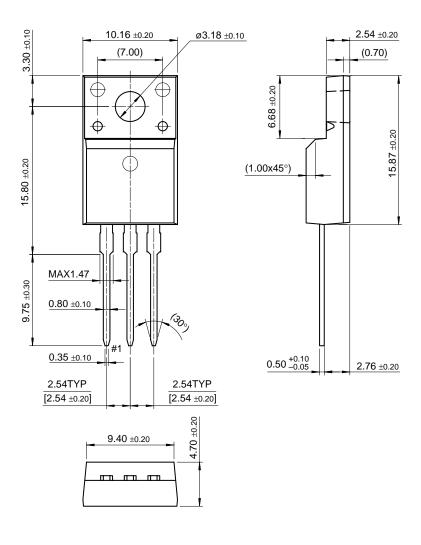


Figure 5. Power Derating

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# **Package Demensions**

# TO-220F



Dimensions in Millimeters

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